



## UV-TIAMO-A8

- SiC UV Photodiode
- Integrated Transimpedance Amplifier
- Sensitivity Range: 309-367 nm
- Max. Irradiance: 180 mW/cm<sup>2</sup>
- TO-5 Can, with Attenuator



### Description

UV-TIAMO devices are 5 Volt powered UV photodetectors with integrated amplifier converting UV radiation into a 0 ... 5V voltage output. The Vout pin can be directly connected to a controller, a voltmeter or any other data analyzing device with voltage input.

Highly modern electronic components and a hermetically sealed metal housing with UV glass window eliminates noise caused by parasitic resistance paths inside the package or EMI. UV-TIAMO series is a perfect solution for each industrial UV sensing application starting from flame detection at pW/cm<sup>2</sup> level up to UV curing lamp control at W/cm<sup>2</sup> level. This thirteen orders of magnitude range is covered by ten different UV-TIAMO devices that differ by their sensitivity.

**UV-TIAMO-A8** is specified with irradiance limits of **18 μW/cm<sup>2</sup> - 180 mW/cm<sup>2</sup>** and a responsivity range of **309 – 367 nm**

The UV-TIAMO series are produced as UV broadband sensors or with filters for selective measurement.

### UV-TIAMO-A Series

Part Number	Responsivity	Irradiance Limits [5V, λ <sub>peak</sub> ]
UV-TIAMO-A1	λ <sub>max</sub> = 275 nm, λ <sub>S10%</sub> = 225 – 287 nm	1.8 pW/cm <sup>2</sup> - 18 nW/cm <sup>2</sup>
UV-TIAMO-A2		18 pW/cm <sup>2</sup> - 180 nW/cm <sup>2</sup>
UV-TIAMO-A3		180 pW/cm <sup>2</sup> - 1.8 μW/cm <sup>2</sup>
UV-TIAMO-A4		1.8 nW/cm <sup>2</sup> - 18 μW/cm <sup>2</sup>
UV-TIAMO-A5		18 nW/cm <sup>2</sup> - 180 μW/cm <sup>2</sup>
UV-TIAMO-A6		180 nW/cm <sup>2</sup> - 1.8 mW/cm <sup>2</sup>
UV-TIAMO-A7		1.8 μW/cm <sup>2</sup> - 18 mW/cm <sup>2</sup>
<b>UV-TIAMO-A8</b>		<b>18 μW/cm<sup>2</sup> - 180 mW/cm<sup>2</sup></b>
UV-TIAMO-A9		180 μW/cm <sup>2</sup> - 1.8 W/cm <sup>2</sup>
UV-TIAMO-A10		1.8 mW/cm <sup>2</sup> - 18 W/cm <sup>2</sup>



## Maximum Ratings

Parameter	Symbol	Values		Unit
		Min.	Max.	
Operating Temperature	$T_{CASE}$	- 25	+ 85	°C
Storage Temperature	$T_{STG}$	- 40	+ 100	°C
Lead Solder Temperature *	$T_{SLD}$		+ 300	°C

\* must be completed within 5 seconds

## General Characteristics ( $T_{CASE}=25^{\circ}C$ , $V_{SUPPLY}=+5V$ )

Parameter	Symbol	Min.	Values	Max.	Unit
			Typ.		
Supply Voltage	$V_{SUPPLY}$	2.5		5.0	V
Saturation Voltage	$V_{SAT}$		$V_{SUPPLY} -5\%$		V
Dark Offset Voltage	$V_{OFFSET}$		50		$\mu V$
Temperature Coefficient	$T_C$			-0.3	%/K
Current Consumption	$I$		150		$\mu A$
Bandwidth (-3 dB)	$\Theta$		15		Hz
Rise Time (63%)	$t_r$		69		ms

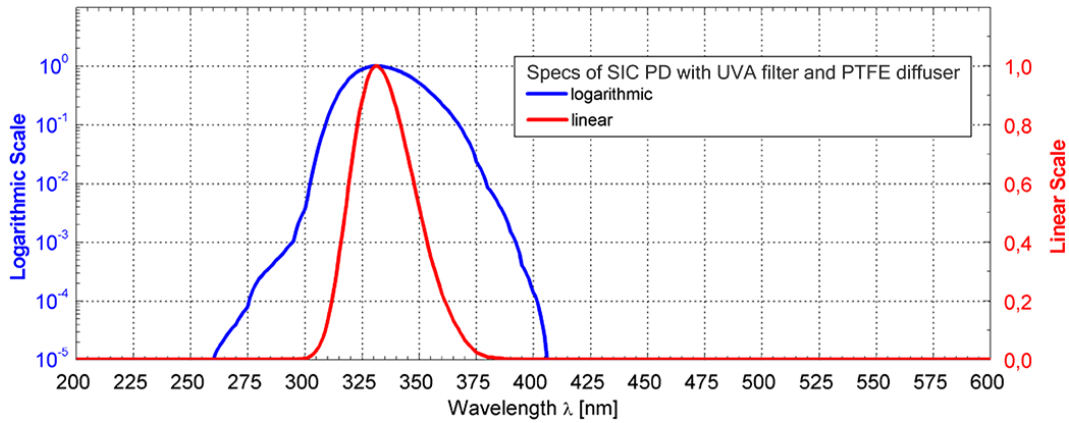
## Spectral Characteristics ( $T_{CASE}=25^{\circ}C$ , $V_{SUPPLY}=+5V$ )

Parameter	Symbol	Min.	Values	Max.	Unit
			Typ.		
Broadband Sensitivity	$S$	0.0018		180	$mW/cm^2$
Sensitivity at Peak	$S_{max}$		28		$mV/mW/cm^2$
Wavelength of max. Spectral Sensitivity	$\lambda_{max}$		331		nm
Sensitivity Range ( $S=0.1 \cdot S_{max}$ )		309		367	nm
Visible Blindness ( $S_{max}/S_{>405nm}$ )	$VB$	$10^{10}$			

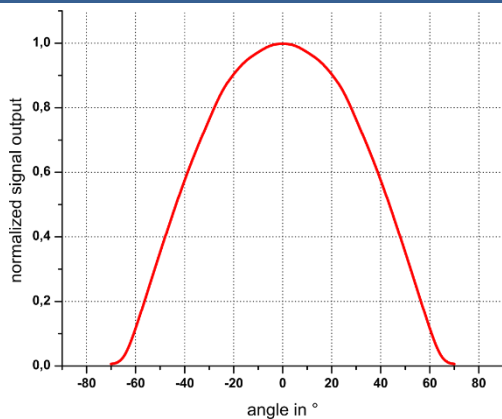


## Performance Characteristics

### Spectral Response



### Field of View



## Outline Dimensions

### TO-5 with attenuator

